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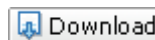
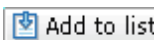
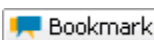
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**Electrical properties of thermally evaporated doped and undoped films of CdSe**[Borah, M.N.](#)<sup>a</sup> , [Chaliha, S.](#)<sup>a</sup> , [Sarmah, P.C.](#)<sup>b</sup>  , [Rahman, A.](#)<sup>a</sup> <sup>a</sup> Department of Physics, Gauhati University, Guwahati 781014<sup>b</sup> Electronics Department, **Regional Research Laboratory, Jorhat** 785006**Abstract**

Electrical characteristics of Ag-doped and undoped films of CdSe have been reported. The activation energies at lower and elevated temperatures have been found to be 0.22 and 0.6eV, respectively. The Sn/CdSe junction exhibits Schottky barrier characteristics with diode ideality factor deviating from unity. Barrier height obtained from C-V plot and J- V plot are 0.8 and 0.72eV, respectively. The junction has been endowed with high series resistance.

**Author Keywords**

Activation energy; Cadmium selenide; Electrical properties; Schottky barrier

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